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### FDS6875 Dual P-Channel 2.5V Specified PowerTrench<sup>™</sup> MOSFET

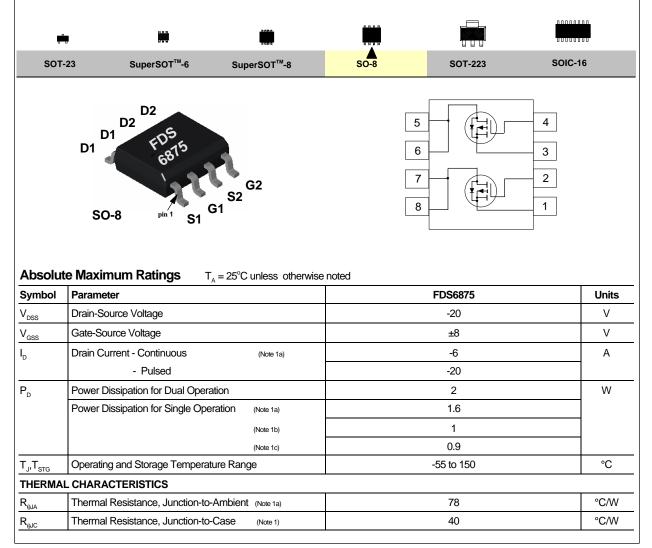
#### **General Description**

These P-Channel 2.5V specified MOSFETs are produced using ON Semiconductor's advanced PowerTrench process that has been especially tailored to minimize the on-state resistance and yet maintain low gate charge for superior switching performance.

These devices are well suited for portable electronics applications: load switching and power management, battery charging and protection circuits.

#### Features

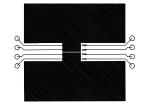
- $\begin{array}{c|c} \bullet & -6 \text{ A, -20 V. } R_{\text{DS(ON)}} = 0.030 \ \Omega & @ \ \text{V}_{\text{GS}} = -4.5 \ \text{V,} \\ R_{\text{DS(ON)}} = 0.040 \ \Omega & @ \ \text{V}_{\text{GS}} = -2.5 \ \text{V.} \end{array}$
- Low gate charge (23nC typical).
- High performance trench technology for extremely low R<sub>DS(ON)</sub>.
- High power and current handling capability.



Symbol	Parameter	Conditions		Min	Тур	Max	Units
OFF CHAR	ACTERISTICS	·		•		•	
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	$V_{GS} = 0 V, I_{D} = -250 \mu A$		-20			V
$\Delta BV_{DSS} / \Delta T_{J}$	Breakdown Voltage Temp. Coefficient	$I_{D}$ = -250 µA, Referenced t	to 25 °C		-21		mV/°C
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{DS} = -16 V, V_{GS} = 0 V$				-1	μA
			T <sub>J</sub> = 55°C			-10	μA
	Gate - Body Leakage, Forward	$V_{GS} = 8 V, V_{DS} = 0 V$				100	nA
GSSR	Gate - Body Leakage, Reverse	$V_{GS} = -8 V, V_{DS} = 0 V$				-100	nA
	CTERISTICS (Note 2)						
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$		-0.4	-0.8	-1.5	V
$\Delta V_{GS(th)} / \Delta T_J$	Gate Threshold Voltage Temp. Coefficient	$I_{\rm D}$ = 250 µA, Referenced to 25 °C			2.8		mV/°C
R <sub>DS(ON)</sub>	Static Drain-Source On-Resistance	$V_{GS} = -4.5 \text{ V}, I_{D} = -6 \text{ A}$			0.024	0.03	Ω
			T <sub>J</sub> =125°C		0.033	0.048	
		$V_{GS} = -2.5 \text{ V}, I_{D} = -5.3 \text{ A}$	<u>, -</u>		0.032	0.04	
D(ON)	On-State Drain Current	$V_{GS} = -4.5 \text{ V}, V_{DS} = -5 \text{ V}$		-20			Α
9 <sub>FS</sub>	Forward Transconductance	$V_{DS} = -4.5 \text{ V}, I_{D} = -6 \text{ A}$			22		S
DYNAMIC (	CHARACTERISTICS						
C <sub>iss</sub>	Input Capacitance	$V_{DS} = -10 \text{ V}, V_{GS} = 0 \text{ V},$ f = 1.0 MHz			2250		pF
C <sub>oss</sub>	Output Capacitance				500		pF
C <sub>rss</sub>	Reverse Transfer Capacitance				200		pF
SWITCHING	CHARACTERISTICS (Note 2)					-	
t <sub>D(on)</sub>	Turn - On Delay Time	$V_{DS}$ = -10 V, $I_{D}$ = -1 A $V_{GEN}$ = -4.5 V, $R_{GEN}$ = 6 $\Omega$			8	16	ns
t,	Turn - On Rise Time				15	27	ns
D(off)	Turn - Off Delay Time				98	135	ns
t,	Turn - Off Fall Time				35	55	ns
Qg	Total Gate Charge	$V_{\rm DS} = -10 \text{ V}, \ \text{I}_{\rm D} = -6 \text{ A},$			23	31	nC
Q <sub>gs</sub>	Gate-Source Charge	V <sub>GS</sub> = -5 V			3.9		nC
Q <sub>gd</sub>	Gate-Drain Charge				5.5		nC
DRAIN-SOU	IRCE DIODE CHARACTERISTICS AND MAX	IMUM RATINGS					
l <sub>s</sub>	Maximum Continuous Drain-Source Diode Forward Current					-1.3	Α
V <sub>SD</sub>	Drain-Source Diode Forward Voltage $V_{GS} = 0 \text{ V}, \text{ I}_{S} = -1.3 \text{ A} \text{ (Note 2)}$				-0.7	-1.2	V

Notes:

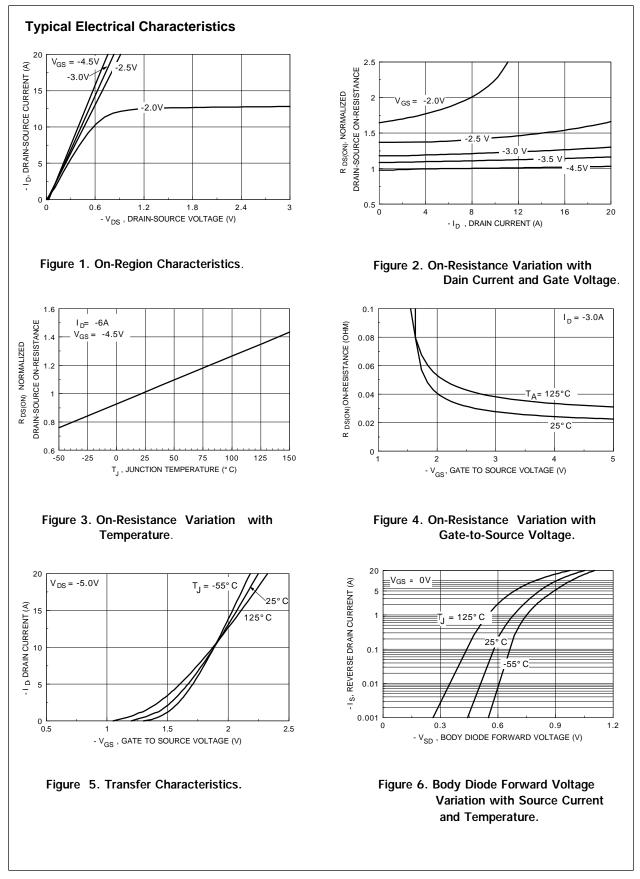
1. R<sub>BW</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R<sub>BW</sub> is guaranteed by design while R<sub>BW</sub> is determined by the user's board design.



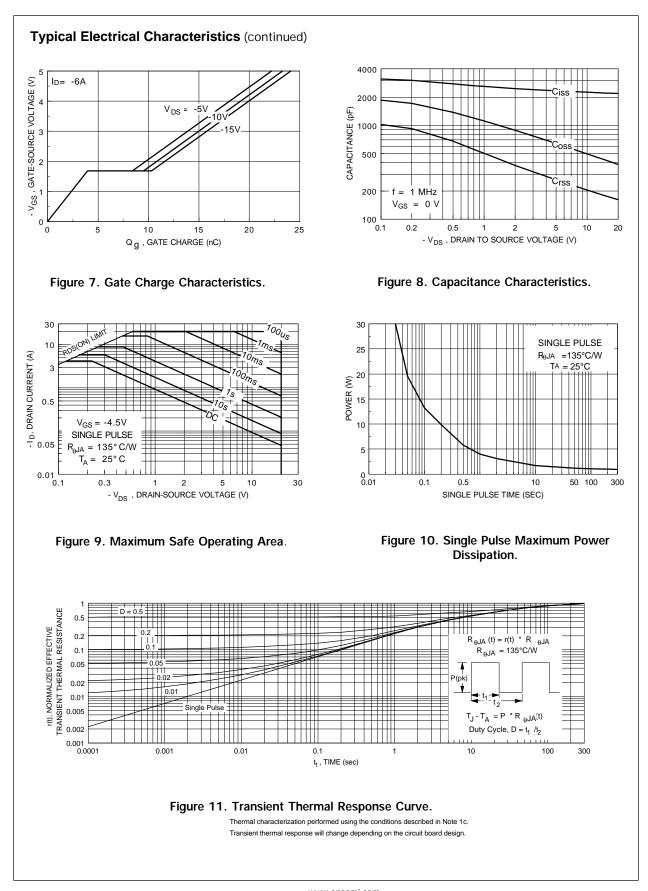
a. 78°C/W on a 0.5 in<sup>2</sup> pad of 2oz copper. b. 125°C/W on a 0.02 in<sup>2</sup> pad of 2oz copper. c. 135°C/W on a 0.003 in<sup>2</sup> pad of 2oz copper.

Scale 1 : 1 on letter size paper

2. Pulse Test: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$  2.0%.



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